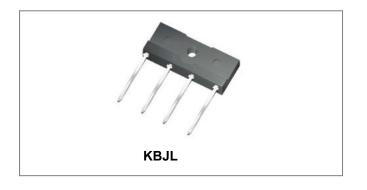


KBJL10J THRU KBJL10M

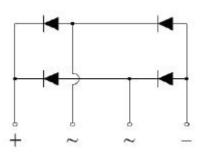
Technical Data Data Sheet N2406, Rev. A



KBJL10J THRU KBJL10M Glass Passivated Single-Phase Bridge Rectifiers



Circuit Diagram



Features

- Thin Single In-Line package;
- Ideal for printed circuit boards;
- Glass Passivated chip junction;
- Low profile package;
- High Surge current capability;
- High case dielectric strength of 2000 VRMS;
- Plastic package has Underwrites Laboratory Flammability Classification 94V-0;
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

- Case: KBJL;
- Epoxy meets UL-94V-0 Flammability rating;
- Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102;
- High temperature soldering guaranteed: Solder Dip 275℃, 40seconds;
- Polarity: As marked on body;
- Mounting Torgue: 5.7cm-kg (5.0 inches-lbs) max;
- Recommend Torgue: Mounting Torgue:
- 5.7cm-kg (5inches-lbs);
- Weight: 2.6 g (approximately)

Maximum Ratings @T_A=25°C unless otherwise specified

Type Number	Symbol	KBJL10J	KBJL10K	KBJL10M	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm V _{rwm} V _{dc}	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	420	560	700	V
$\label{eq:maximum} \begin{array}{ll} \mbox{Maximum average forward} & T_c=155\ensuremath{^\circ\!C}^\circ$	I _{F(AV)}	10 ⁽¹⁾ 3.1 ⁽²⁾		A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave	IFSM	180		А	
Rating of fusing (t<8.3ms)	l ² t		135		A ² s

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KBJL10J THRU KBJL10M

RoHS 🗭

Electrical Characteristics@T_A=25°C unless otherwise specified

Type Number	Symbol	KBJL10J	KBJL10K	KBJL10M	Units
Maximum Forward Voltage @ I_F =5A, T_A = 25°C	VF	0.98			V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I _{RM}	5.0 150			μΑ

* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Type Number	Symbol	KBJL10J	KBJL10K	KBJL10M	Units
Typical Thermal Resistance	R _{θJC} R _{θJA}	1.8 ^(1,3) 25 ⁽²⁾			°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175			°C

(1). Unit case mounted on AI plate heatsink;

(2). Units mounted on PCB without heatsink;

(3). Recommended mounting position is to bolt down on heatsink with silicone thermal compound for maximum heat transfer with #6 screw.

Ratings and Characteristics Curves

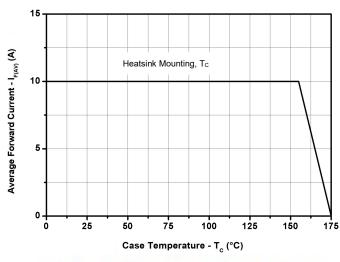
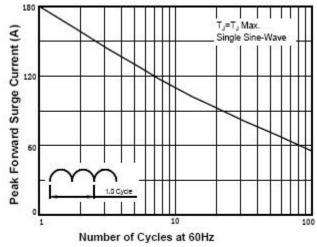
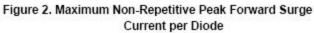


Figure 1. Derating Curve Output Rectified Current

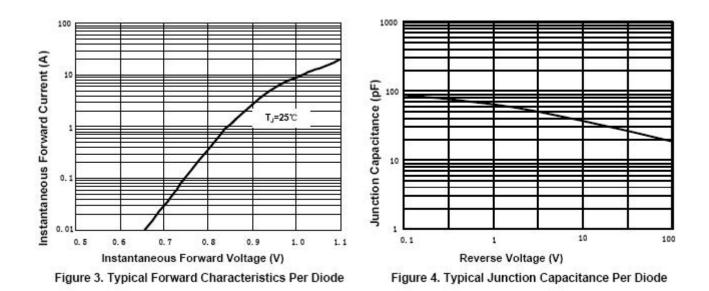






KBJL10J THRU KBJL10M

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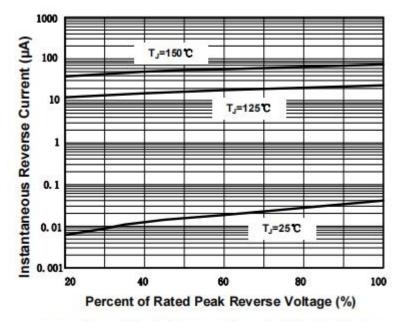


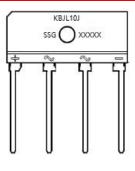
Figure 5. Typical Reverse Characteristics Per Diode



Ordering Information

Device	Package	Plating	Shipping
KBJL10J THRU KBJL10M	KBJL	Pure Sn	20pcs / tube

Marking Diagram



Where XXXXX is YYWWL

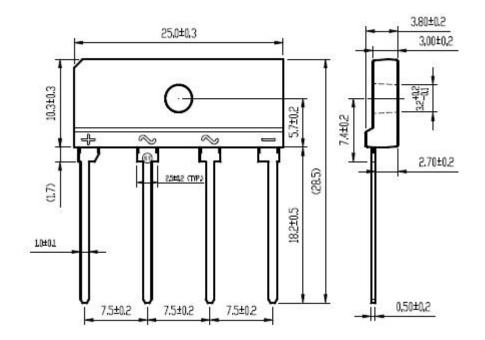
YY

L

KBJL10J = Type Number = SSG SSG = Year ŴŴ = Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Mechanical Dimensions KBJL (MM)





KBJL10J THRU **KBJL10M**







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